

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1. (Currently Amended) A semiconductor device, comprising:  
a mounting substrate having a step portion in a periphery thereof;  
a conductive pattern formed on a surface of the mounting substrate located inside the step portion;  
a semiconductor element fixed to the mounting substrate and electrically connected to the conductive pattern; and  
sealing resin covering the surface of the mounting substrate and the step portion to seal the semiconductor element.
2. (Original) The semiconductor device according to claim 1, wherein the conductive pattern comprises a bonding pad electrically connected to the semiconductor element through a fine metallic wire and a plating line extending from the bonding pad to the step portion.
3. (Original) The semiconductor device according to claim 2, wherein a plurality of the bonding pads are arranged so as to surround the semiconductor element, further comprising a wiring portion extending from each of the plurality of bonding pads under the semiconductor element.
4. (Withdrawn) A method of manufacturing a semiconductor device, comprising:  
forming first conductive patterns which constitute units and common plating lines on a front surface of a substrate, each of the units comprising bonding pads and plating lines

extending from the respective bonding pads to a periphery, the common plating lines electrically connecting the plating lines of the units;

forming second conductive patterns on a back surface of the substrate, the second conductive patterns being electrically connected to the respective first conductive patterns;

forming a plated film to a surface of the first conductive patterns by electroplating using the common plating lines;

forming grooves on the front surface of the substrate by dicing the front surface of the substrate including the common plating lines to electrically separate the conductive patterns;

placing semiconductor elements on the front surface of the substrate;

providing sealing resin which fills the grooves and seals the semiconductor elements; and

separating the semiconductor elements by dicing the substrate and the sealing resin at borders of the units.

5. (Withdrawn) The method of manufacturing a semiconductor device according to claim 4, wherein the units are arranged in a matrix, and the common plating lines extend along the borders of the units into a grid.